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STMicroelectronics STPS15L30CDJFTR

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STPS15L30CDJF

Low drop power Schottky rectifier

Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low forward voltage drop
- Low thermal resistance
- High avalanche capability specified

Description

Dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in PowerFLAT™, this device is intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.

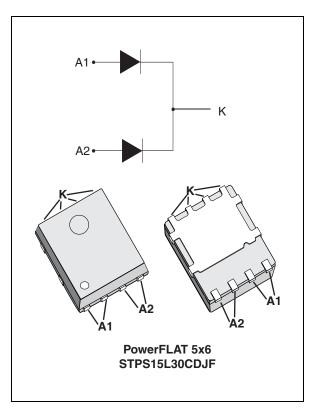


Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 7.5 A
V_{RRM}	30 V
T _j (max)	150 °C
V _F (typ)	0.34 V

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1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter			Value	Unit	
V _{RRM}	Repetitive peak reverse voltage			30	V	
I _{F(RMS)}	Forward rms current			10	Α	
1	Average forward current $\delta = 0.5$	T _c = 140 °C	Per diode	7.5	Α	
I _{F(AV)}	Average lorward current $\delta = 0.5$		Per device	15	, A	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			75	Α	
I _{RRM}	Peak repetitive reverse current	k repetitive reverse current $t_p = 2 \mu s \text{ square } F = 1 \text{ kHz}$		1	Α	
P _{ARM}	epetitive peak avalanche power $t_p = 1 \mu s T_j = 25 ^{\circ}C$		2800	W		
T _{stg}	Storage temperature range			-65 to + 175	°C	
Tj	Maximum operating junction temperature (1)			150	°C	

^{1.} $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit	
В		Per diode	2.5	
R _{th(j-c)}	Junction to case Total		1.6	°C/W
R _{th(c)}	Coupling	0.7		

When diodes 1 and 2 are used simultaneously:

 $\Delta T_j(diode 1) = P(diode 1) \times R_{th(j-c)}(per diode) + P(diode 2) \times R_{th(c)}$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage	T _j = 25 °C	V - V	-	-	1	mA
current	T _j = 125 °C	$V_R = V_{RRM}$	-	70	140	mA	
V _F ⁽¹⁾ Forward voltage drop		T _j = 25 °C	I _F = 7.5 A	-	-	0.48	
	Forward voltage drop	T _j = 125 °C	I _F = 7.5 A	-	0.34	0.39	V
	Polward voltage drop	T _j = 25 °C	I _F = 15 A	-	-	0.57	V
		T _j = 125 °C	I _F = 15 A	-	0.44	0.51	

^{1.} Pulse test: $t_p = 380 \mu s$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.27 \text{ x } I_{F(AV)} + 0.016 I_{F}^{2}_{(RMS)}$$

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0

0

25

STPS15L30CDJF Characteristics

Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)

(δ = 0.5, per diode)

T_{amb}(°C)

100

125

150

75

ambient temperature

Average forward current versus

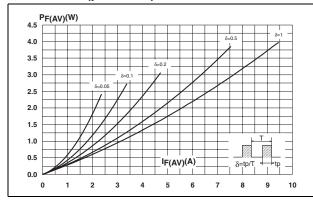
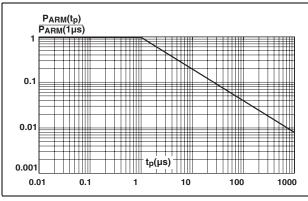


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature

50



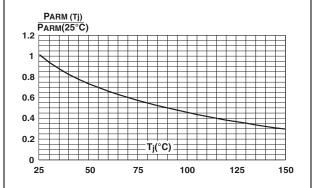
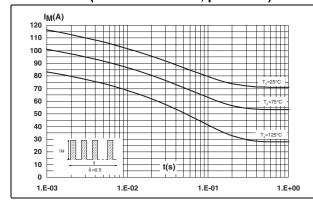
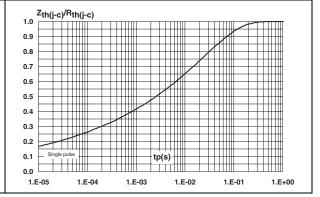


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 6. Relative variation of thermal impedance, junction to case, versus pulse duration





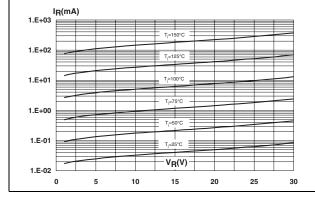
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Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)



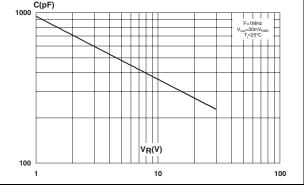
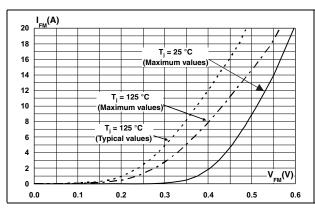
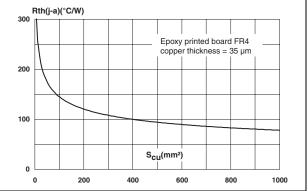


Figure 9. Forward voltage drop versus forward current (per diode)

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead





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STPS15L30CDJF Package information

2 Package information

- Epoxy meets UL94,V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 5. PowerFLAT 5x6 dimensions

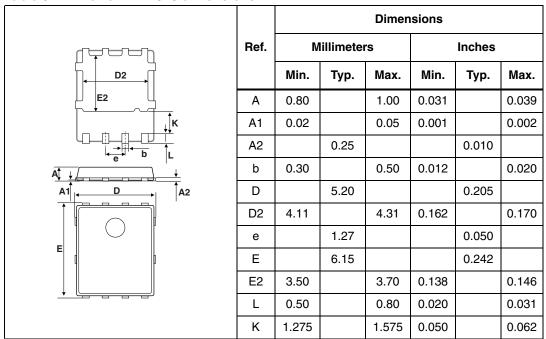
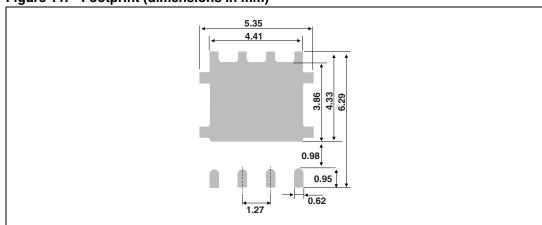


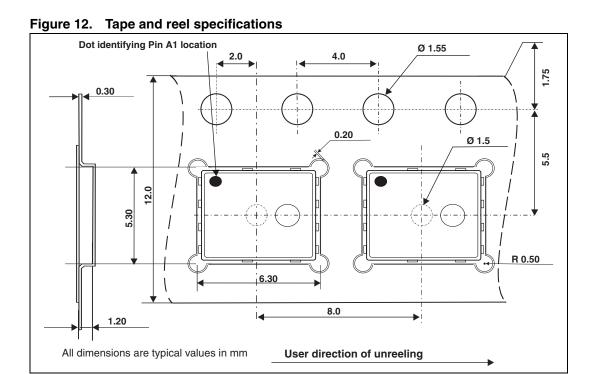
Figure 11. Footprint (dimensions in mm)





Ordering information

STPS15L30CDJF



3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS15L30CDJFTR	PS15 L30C	PowerFLAT 5x6	0.095 g	3000	Tape and reel

4 Revision history

Table 7. Document revision history

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Date	Revision	Changes		
13-May-2009	1	First issue.		
09-Nov-2009	2	Updated <i>Table 1</i> .		
30-Jul-2010	3	Replace Power QFN with PowerFLAT. Updated Figure 9.		
18-May-2011	4	Added reference E in <i>Table 5</i> . Updated package graphics. Removed dash from order code and updated marking in <i>Table 6</i> . Added <i>Figure 12</i> .		

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Distributor of STMicroelectronics: Excellent Integrated System Limited Datasheet of STPS15L30CDJFTR - DIODE ARRAY SCHOTTKY 30V 7.5A

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